TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7W14FU, TC7W14FK

#### Schmitt Inverter

The TC7W14 is high speed  $\rm C^2MOS$  Schmitt Inverter fabricated with silicon gate  $\rm C^2MOS$  technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the  $C^2MOS$  low power dissipation.

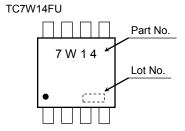
Pin configuration and function are the same as the TC7WU04 but the inputs have 25% VCC hysteresis and with its Schmitt trigger function, the TC7W14 can be used as a line receivers which will receive slow input signals.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

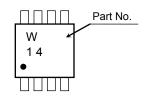
#### **Features**

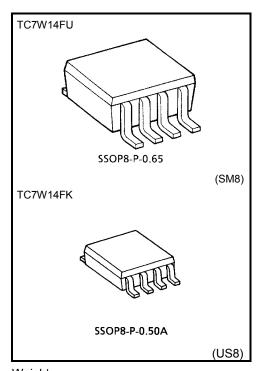
- High speed: t<sub>pd</sub> = 11 ns (typ.) at V<sub>CC</sub> = 5 V
- Low power dissipation:  $I_{CC} = 1\mu A$  (max) at Ta = 25°C
- High noise immunity: V<sub>H</sub> = 1.1 V at V<sub>CC</sub> = 5V
- Output drive capability: 10 LSTTL loads
- Symmetrical output impedance: |I<sub>OH</sub>| = I<sub>OL</sub> = 4mA (min)
- Balanced propagation delays: t<sub>pLH</sub> ≃ t<sub>pHL</sub>
- Wide operating voltage range: V<sub>CC</sub> (opr) = 2 to 6V

## Marking



TC7W14FK





Weight SSOP8-P-0.65: 0.02 g (typ.) SSOP8-P-0.50A: 0.01 g (typ.)

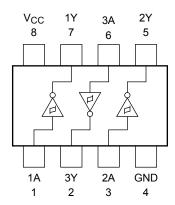
## Absolute Maximum Ratings (Ta = 25°C)

| Characteristics                    | Symbol           | Rating                     | Unit  |
|------------------------------------|------------------|----------------------------|-------|
| Supply voltage range               | V <sub>CC</sub>  | –0.5 to 7                  | V     |
| DC input voltage                   | V <sub>IN</sub>  | $-0.5$ to $V_{CC}$ + $0.5$ | ٧     |
| DC output voltage                  | V <sub>OUT</sub> | $-0.5$ to $V_{CC}$ + $0.5$ | ٧     |
| Input diode current                | I <sub>IK</sub>  | ±20                        | mA    |
| Output diode current               | lok              | ±20                        | mA    |
| DC output current                  | lout             | ±25                        | mA    |
| DC V <sub>CC</sub> /ground current | Icc              | ±25                        | mA    |
| Dower discipation                  | PD               | 300 (SM8)                  | mW    |
| Power dissipation                  | FD               | 200 (US8)                  | IIIVV |
| Storage temperature range          | T <sub>stg</sub> | -65 to 150                 | °C    |
| Lead temperature (10 s)            | TL               | 260                        | °C    |

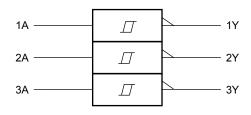
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### Pin Configuration (top view)



#### **Logic Diagram**



## **Truth Table**

| Α | Y |
|---|---|
| L | Н |
| Н | L |

# **Operating Ranges**

| Characteristics             | Symbol           | Rating               | Unit |
|-----------------------------|------------------|----------------------|------|
| Supply voltage              | V <sub>CC</sub>  | 2 to 6               | V    |
| Input voltage               | V <sub>IN</sub>  | 0 to V <sub>CC</sub> | V    |
| Output voltage              | V <sub>OUT</sub> | 0 to V <sub>CC</sub> | V    |
| Operating temperature range | T <sub>opr</sub> | -40 to 85            | °C   |

# **Electrical Characteristics**

### **DC Electrical Characteristics**

| Characteristics Symbol Test Condition |             |  | -  | Ta = 25°C                  |     |      | Ta = -40<br>to 85°C |      |      |      |             |
|---------------------------------------|-------------|--|--|----------------------------|-----|------|---------------------|------|------|------|-------------|
|                                       |             | V <sub>CC</sub> (V)  | Min                                      | Тур.                       | Max | Min  | Max                 | Unit |      |      |             |
|                                       |             |  |  |                            | 2.0 | 1.0  | 1.25                | 1.5  | 1.0  | 1.5  |             |
| High level                            | High level  | V <sub>P</sub>   | _  |                            | 4.5 | 2.3  | 2.7                 | 3.15 | 2.3  | 3.15 |             |
| Threshold                             |             |  |  |                            | 6.0 | 3.0  | 3.5                 | 4.2  | 3.0  | 4.2  | V           |
| voltage                               |             |  |  |                            |     | 0.3  | 0.65                | 0.9  | 0.3  | 0.9  | V           |
|                                       | Low level   | V <sub>N</sub>   | _  |                            | 4.5 | 1.13 | 1.6                 | 2.0  | 1.13 | 2.0  |             |
|                                       |             |  |  |                            | 6.0 | 1.5  | 2.3                 | 2.6  | 1.5  | 2.6  |             |
|                                       |             |  |  |                            | 2.0 | 0.3  | 0.6                 | 1.0  | 0.3  | 1.0  |             |
| Hysteresis voltage V <sub>H</sub>     |             |  | _  |                            | 0.6 | 1.1  | 1.4                 | 0.6  | 1.4  | V    |             |
|                                       |             |  |  |                            |     | 0.8  | 1.2                 | 1.7  | 8.0  | 1.7  |             |
|                                       |             | High level V <sub>OH</sub>   | $V_{IN} = V_{IL}$                        | I <sub>OH</sub> = -20 μA   | 2.0 | 1.9  | 2.0                 | _    | 1.9  | _    |             |
| High leve                             |             |  |  |                            | 4.5 | 4.4  | 4.5                 | _    | 4.4  | _    |             |
|                                       | High level  |  |  |                            | 6.0 | 5.9  | 6.0                 | _    | 5.9  | _    |             |
|                                       |             |  |  | I <sub>OH</sub> = -4 mA    | 4.5 | 4.18 | 4.31                | _    | 4.13 | _    |             |
| Output                                |             |  |  | $I_{OH} = -5.2 \text{ mA}$ | 6.0 | 5.68 | 5.80                | _    | 5.63 | _    | \ /         |
| voltage  Low level                    |             |  |  | 2.0                        | _   | 0    | 0.1                 | _    | 0.1  | V    |             |
|                                       |             | ow level $V_{OL}$ $V_{IN} = V_{OL}$                                |  | $I_{OL} = 20 \mu A$        | 4.5 | _    | 0                   | 0.1  | _    | 0.1  | -<br>-<br>- |
|                                       | Low level   |  | $V_{IN} = V_{IH}$                        |                            | 6.0 | _    | 0                   | 0.1  | _    | 0.1  |             |
|                                       |             |  |  | I <sub>OL</sub> = 4 mA     | 4.5 | _    | 0.17                | 0.26 | _    | 0.33 |             |
|                                       |             |  |  | I <sub>OL</sub> = 5.2 mA   | 6.0 |      | 0.18                | 0.26 | _    | 0.33 |             |
| Input leakage                         | current     | I <sub>IN</sub>  | V <sub>IN</sub> = V <sub>CC</sub> or GND |                            | 6.0 | _    | _                   | ±0.1 | _    | ±1.0 | μА          |
| Quiescent sup                         | ply current | y current I <sub>CC</sub> V <sub>IN</sub> = V <sub>CC</sub> or GND |  | 6.0                        | _   | _    | 1.0                 | _    | 10.0 | μА   |             |



# AC Electrical Characteristics (C<sub>L</sub> = 15 pF, $V_{CC}$ = 5 V, Ta = 25°C)

| Characteristics        | Symbol                               | Toot Condition | •   | Limit |     |      |
|------------------------|--------------------------------------|----------------|-----|-------|-----|------|
|                        |                                      | Test Condition | Min | Тур.  | Max | Unit |
| Output transition time | t <sub>TLH</sub><br>t <sub>THL</sub> | _              |     | 4     | 8   | ns   |
| Propagation delay time | t <sub>pLH</sub><br>t <sub>pHL</sub> | _              |     | 11    | 21  | ns   |

### AC Electrical Characteristics ( $C_L = 50 \text{ pF}$ , input $t_r = t_f = 6 \text{ ns}$ )

| Characteristics               | Symbol                               | Test Condition |                     | Ta = 25°C |      |     | Ta = -40<br>to 85°C |     | Unit |
|-------------------------------|--------------------------------------|----------------|---------------------|-----------|------|-----|---------------------|-----|------|
|                               |                                      |                | V <sub>CC</sub> (V) | Min       | Тур. | Max | Min                 | Max |      |
| Output transition time        |                                      | _              | 2.0                 | _         | 30   | 75  | _                   | 95  |      |
|                               | t <sub>TLH</sub><br>t <sub>THL</sub> |                | 4.5                 | _         | 8    | 15  | _                   | 19  | ns   |
|                               | THL                                  |                | 6.0                 | _         | 7    | 13  | _                   | 16  |      |
| Propagation delay time        | t <sub>pLH</sub>                     | _              | 2.0                 | _         | 42   | 125 | _                   | 155 |      |
|                               |                                      |                | 4.5                 | _         | 14   | 25  | _                   | 31  | ns   |
|                               |                                      |                | 6.0                 | _         | 12   | 21  | _                   | 26  |      |
| Input capacitance             | C <sub>IN</sub>                      | _              |                     | _         | 5    | 10  | _                   | 10  | pF   |
| Power dissipation capacitance | C <sub>PD</sub>                      |                | (Note)              | _         | 28   | _   | _                   | _   | pF   |

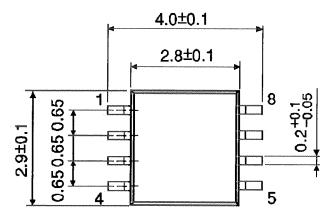
Note: C<sub>PD</sub> is defined as the value of internal equivalent capacitance of IC which is calculated from the operating current consumption without load.

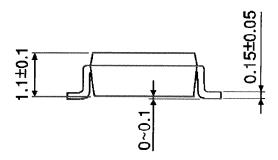
Average operating current can be obtained by the equation hereunder.

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/3 \text{ (per gate)}$ 

# **Package Dimensions**

SSOP8-P-0.65 Unit: mm





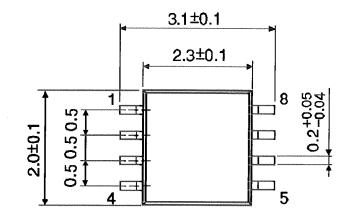
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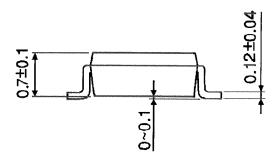
Weight: 0.02 g (typ.)

# **Package Dimensions**

SSOP8-P-0.50A







Weight: 0.01 g (typ.)

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